

Middle Power LED E-Series

0.5W White

SPHWTE1NZA0



Features

- Package : Silicone covered ceramic substrate
- Dimension : 1.2 mm x 1.6 mm
- Technology : Flip Chip
- Chip Configuration : 1 chip
- ESD Voltage : Up to 8 kV
- Viewing Angle: 120°
- Qualifications : The product qualification test will be updated based on the guidelines of AEC-Q102



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1. Characteristics

a) Typical Characteristics

[T_s= 25°C] ^[1]

Item	Symbol	Value	Unit.
Luminous Flux (I _F = 150 mA)	Φ _v	Typ. 65	lm
Forward Voltage (I _F =150 mA)	V _F	Typ. 3.0	V
Viewing Angle	Φ	Typ. 120	°
Reverse Current	I _R	Not designed for reverse operation	
Real Thermal Resistance (Junction to Solder point)	R _{th_J-S (Real)}	Typ. 9.4	K/W
		Max. 11.1	
Electrical Thermal Resistance (Junction to Solder point)	R _{th_J-S (Elec.)}	Typ. 4.8	K/W
		Max. 5.6	
Radian Surface	A	0.865	mm ²

Note:

[1] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25 ms.

b) Absolute Maximum Rating

Item	Symbol	Rating	Unit
Ambient / Operating Temperature	T _a	-40 ~ +125	°C
Storage Temperature	T _{stg}	-40 ~ +125	°C
LED Junction Temperature	T _j	150	°C
Maximum Forward current ^[2] (T _s :25°C) ^[3]	I _F	300	mA
Minimum Forward current ^[2] (T _s :25°C) ^[3]	I _F	50	mA
Maximum Reverse current		Do not apply for reverse current	
ESD Sensitivity ^[4]	-	±8 HBM	kV

Note:

[2] Driving the product at forward current (I_F) below Min. I_F or above Max. I_F may result in unpredictable behavior of the product.

[3] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25 ms

[4] It is included the device to protect the product from ESD.

2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	P	H	W	H	T	E	1	N	Z	A	0	A	B	C	D	E	F

Digit	PKG Information
1 2	company name and Samsung LED PKG (SP for Samsung PKG)
3	power variant (H for automotive high power)
4 5	color variant (WH for automotive white color)
6	LED PKG version (T for 1st version)
7 8	product configuration and type (E1 for E-Series automotive PKG type)
9	lens configuration (N for no lens)
10	max power (Z for 0.5W)
11	Special internal code (A for automotive version)
12	Specific property (0 for default)
13 14	forward voltage property
15 16	CIE coordination property
17 18	luminous flux property

a) Luminous Flux Bins ^[5] ($I_F = 150 \text{ mA}$, $T_s = 25^\circ\text{C}$)

Symbol	Flux Bin Code	Flux Range (lm)	
		Min	Max
Φ_V	B1	55	65
	C1	65	75

b) Voltage Bins ^[5] ($I_F = 150 \text{ mA}$, $T_s = 25^\circ\text{C}$)

Symbol	Voltage Bin Code	Voltage Range (V)	
		Min	Max
V_F	1D	2.75	3.00
	1E	3.00	3.25

Note:

[5] Luminous flux measuring equipment : CAS140CT

Φ_V and V_F tolerances are $\pm 7\%$ and $\pm 0.1\text{V}$, respectively

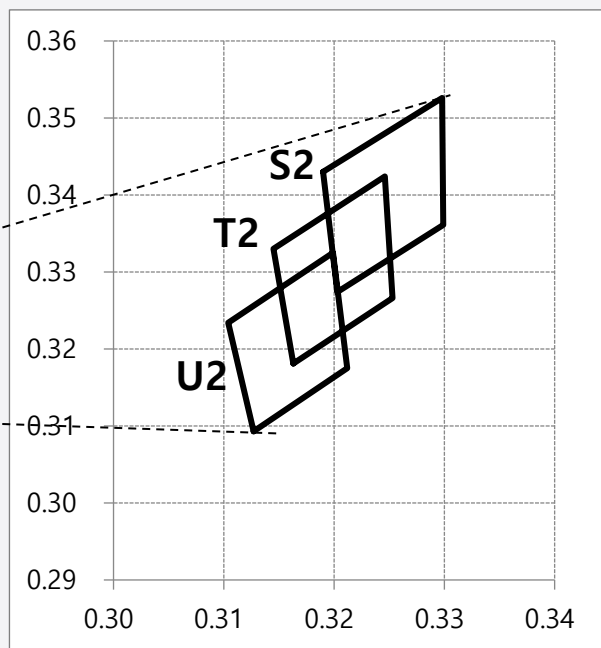
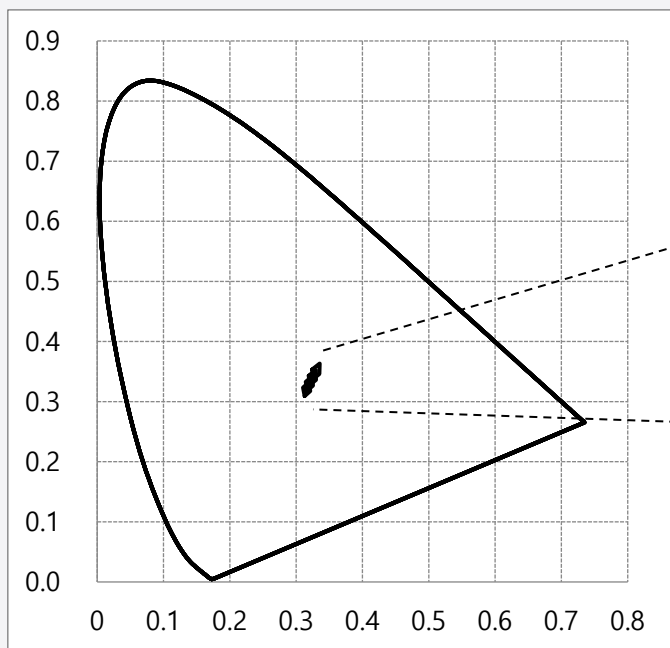
c) Color Bin [6]($I_F = 150 \text{ mA}$)

Symbol	Color Bin Code	Cx				Cy			
Cx, Cy	S2	0.3190	0.3203	0.3299	0.3298	0.3430	0.3274	0.3361	0.3526
	T2	0.3163	0.3145	0.3246	0.3253	0.3181	0.3330	0.3424	0.3266
	U2	0.3127	0.3104	0.3199	0.3212	0.3093	0.3234	0.3325	0.3175

Note

[6] Luminous flux measuring equipment : CAS140CT

Chromaticity coordinates : Cx, Cy according to CIE 1931. Cx and Cy tolerances are ± 0.005 , respectively.

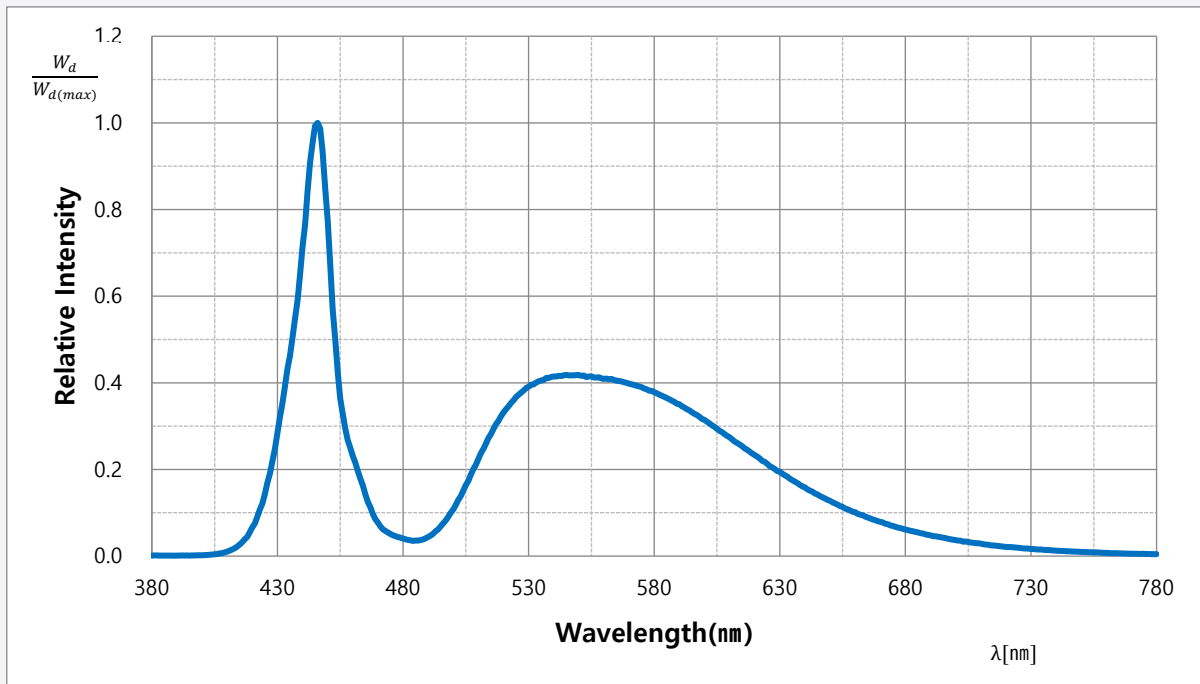


d) Luminous Flux Bins according to Color Bin ($I_F = 150 \text{ mA}$, $T_S = 25 \text{ }^\circ\text{C}$)

Symbol	Flux Bin Code	Flux Range (lm)			
		B1		C1	
		Min	Max	Min	Max
		55	65	65	75
Φ_V	S2				0
	T2		0		0
	U2		0		

3. Typical Characteristics Graphs

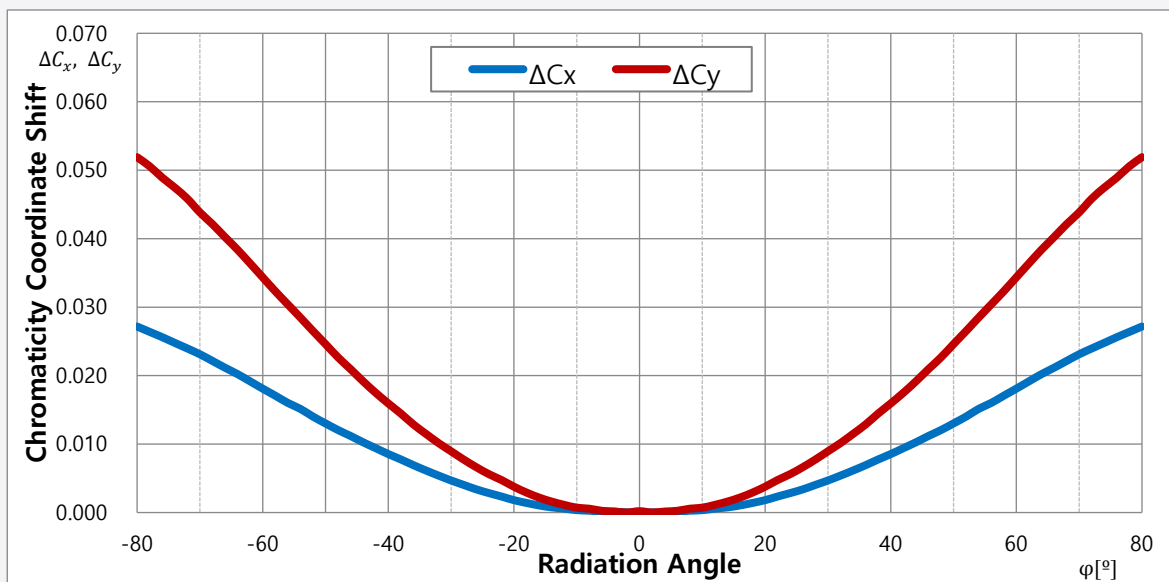
a) Spectrum Distribution ($I_F = 150 \text{ mA}$, $T_S = 25 \text{ }^\circ\text{C}$) [7]



Note: The red content of the light (610~780nm) >5% according to ECE regulation

The UV radiation of the light (250~400nm) $\leq 10^{-5} \text{ W/lm}$ according to ECE regulation

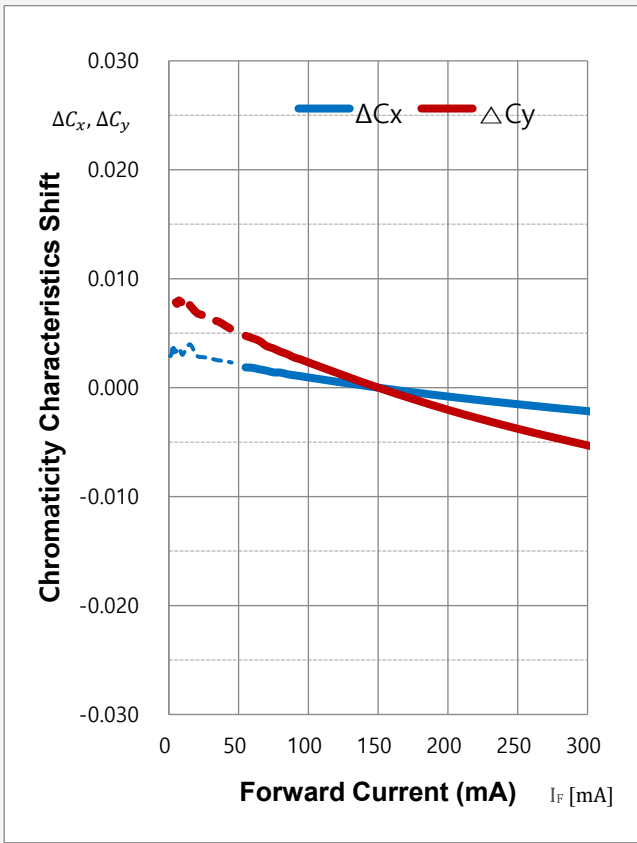
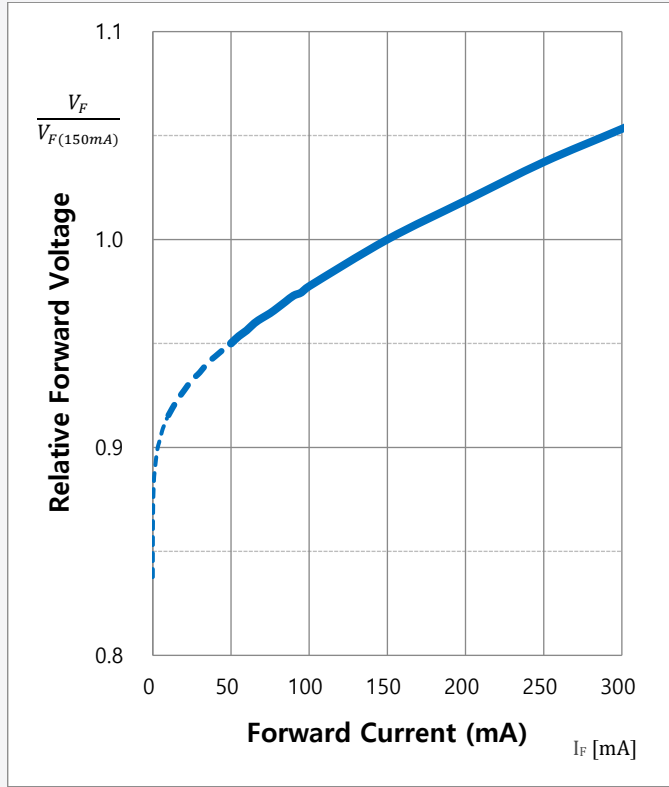
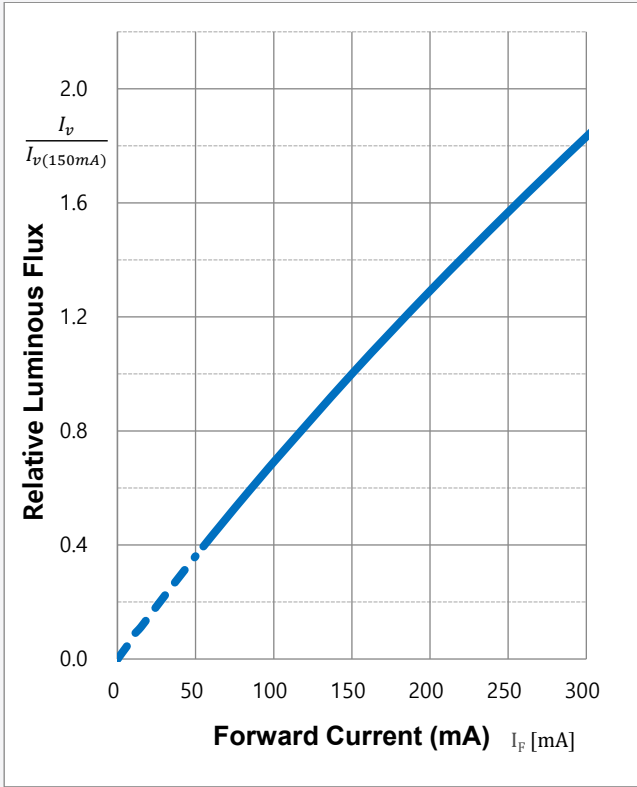
b) Typical Chromaticity Coordinate Shift vs Radiation Angle ($I_F = 150 \text{ mA}$, $T_S = 25 \text{ }^\circ\text{C}$) [7]



Note:

[7] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25 ms

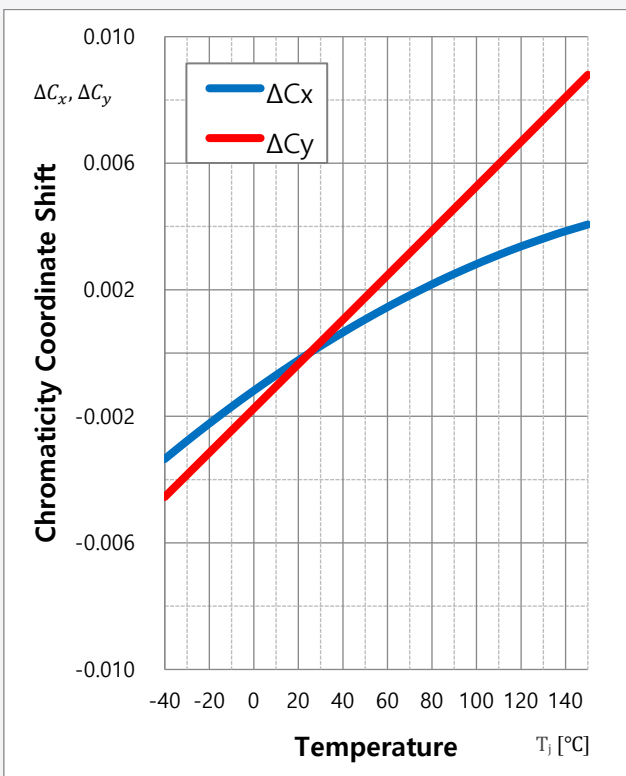
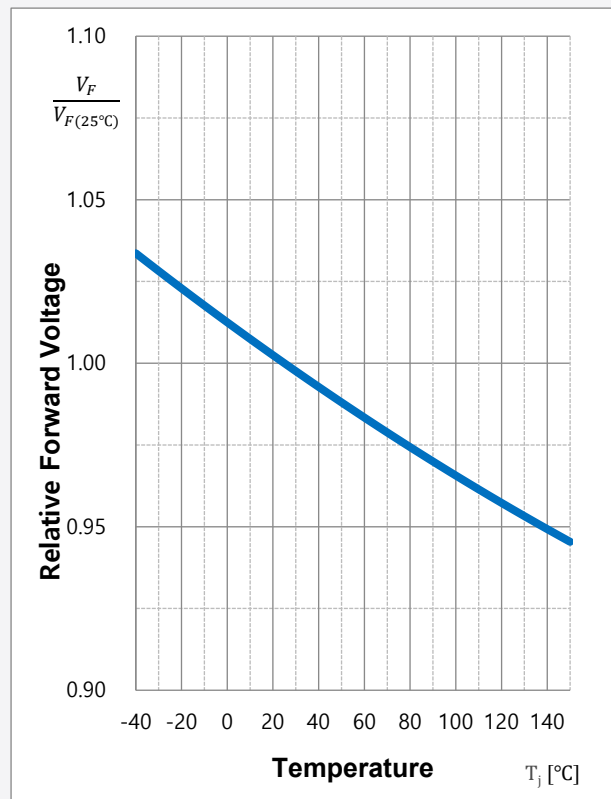
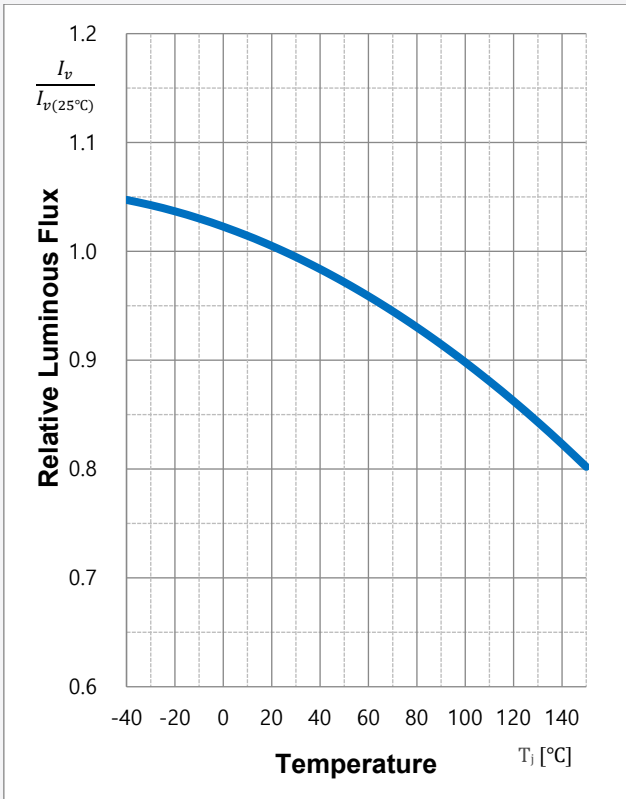
c) Forward Current Characteristics ($T_s = 25\text{ }^\circ\text{C}$) [8]



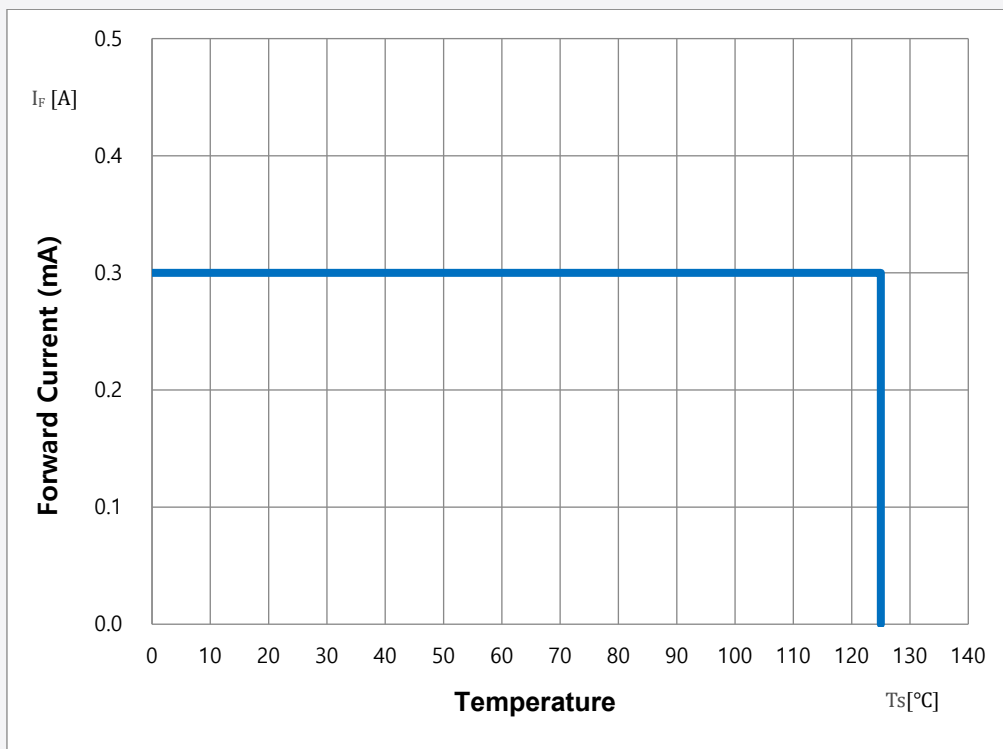
Note:

[8] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25 ms.

d) Temperature Characteristics ($I_F = 150 \text{ mA}$)



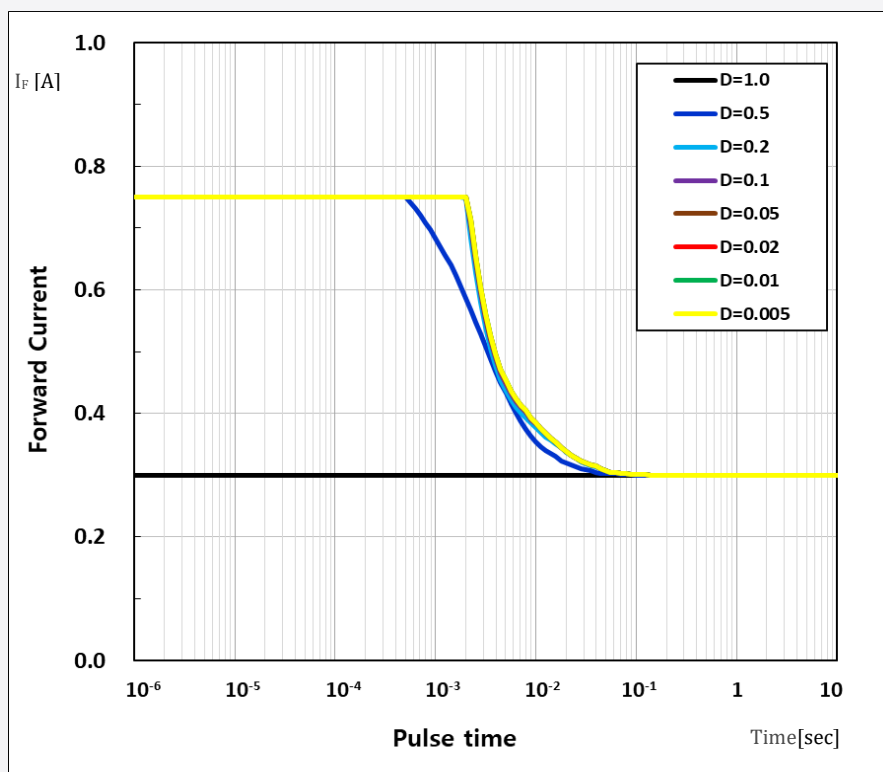
e) Derating Curve ^[9]



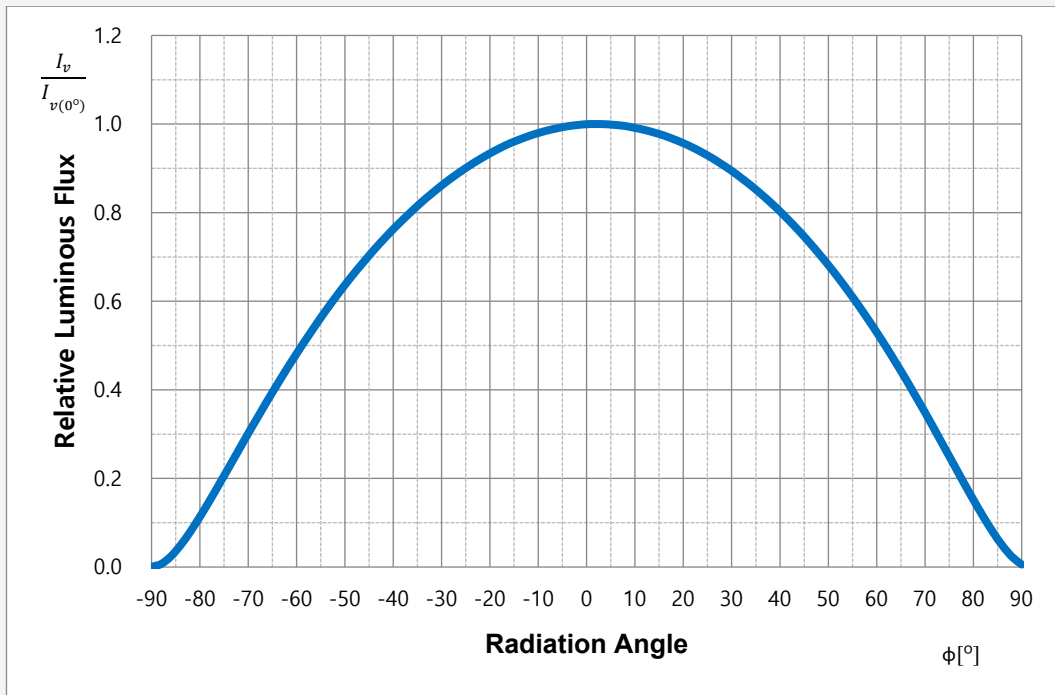
Note:

[9] The measurement condition means that temperature dependence is excluded by applying pulse current for typically 25 ms

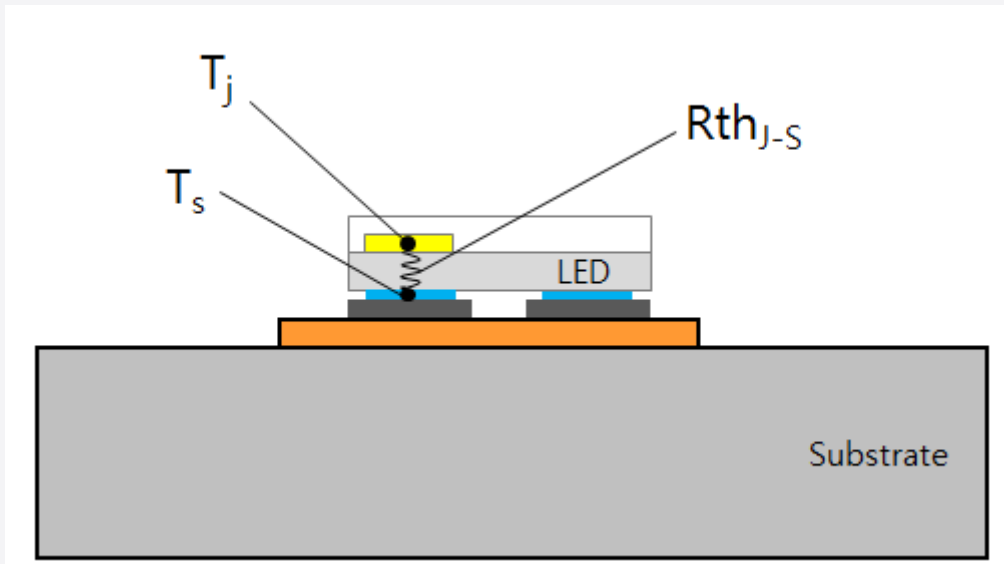
f) Permissible Pulse Handling Capacity ($I_F=f(t_p)$; D : Duty cycle, $T_s=125\text{ }^\circ\text{C}$)



g) Beam Angle Characteristics ($I_F = 150 \text{ mA}$, $T_S = 25 \text{ }^\circ\text{C}$)



4. Soldering Temperature Location

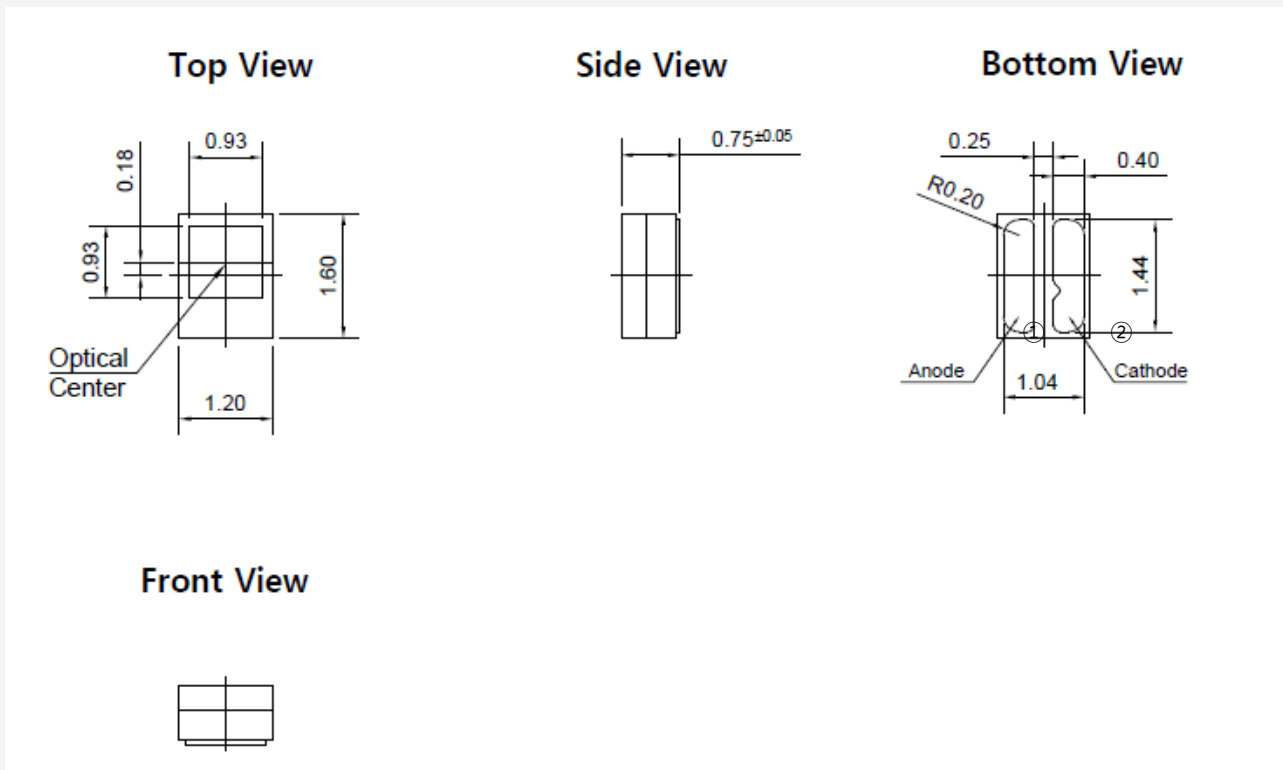


T_j : Temperature of Junction

T_s : Temperature of Solder Pad

$R_{th_{J-S}}$: Thermal Resistance from Junction to Solder Pad

5. Mechanical Dimension



Note:

The dimensions in parentheses are for reference purposes.

Unit: mm, Tolerance: ± 0.1 mm

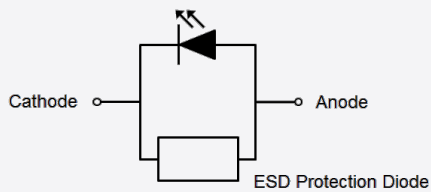
Approximate weight : 4.6mg

a) Pick and Place

Do not place pressure on the resin molded part

It is recommended to use a pick & place nozzle AM03-024820A(Hanhwa Techwin), etc.

b) Electric Schematic Diagram

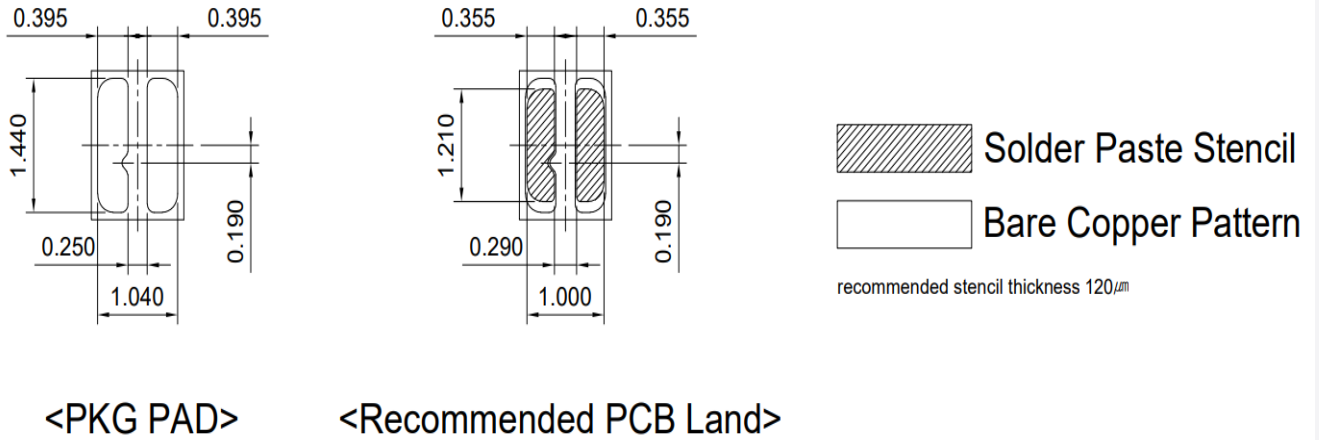


c) Material Information

Description	Material
Substrate	Ceramic Substrate
LED Die	Flip Chip
Phosphor	Phosphor
Zener Diode	Silicon
Wire	Au
Resin Mold	TiO2 Silicone

6. Soldering Conditions

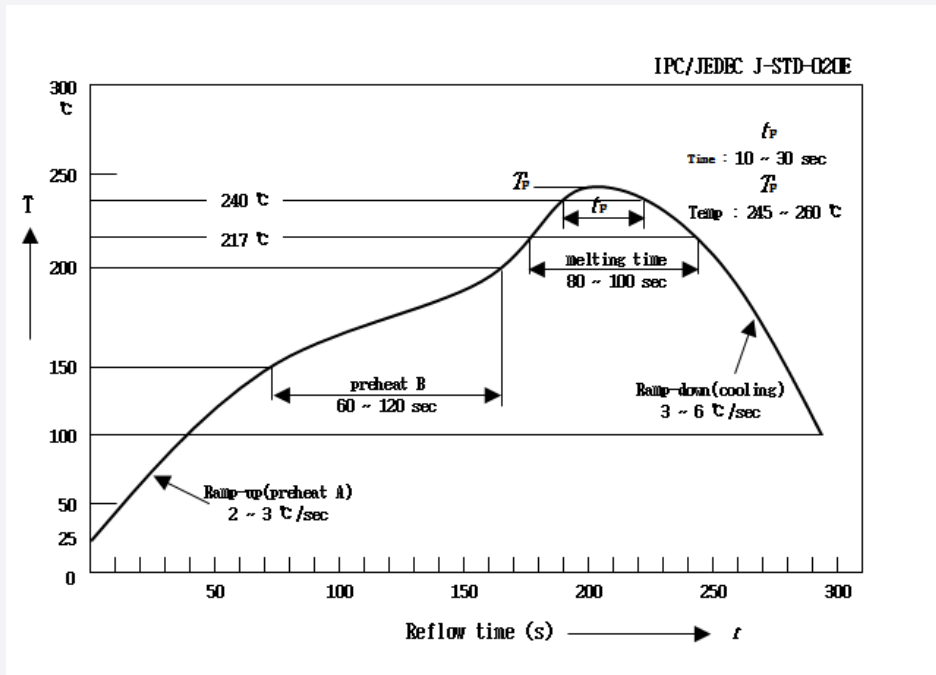
a) Pad Configuration



Notes: mm, Tolerance : ± 0.10 mm, recommended stencil thickness 120 μ m

b) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.

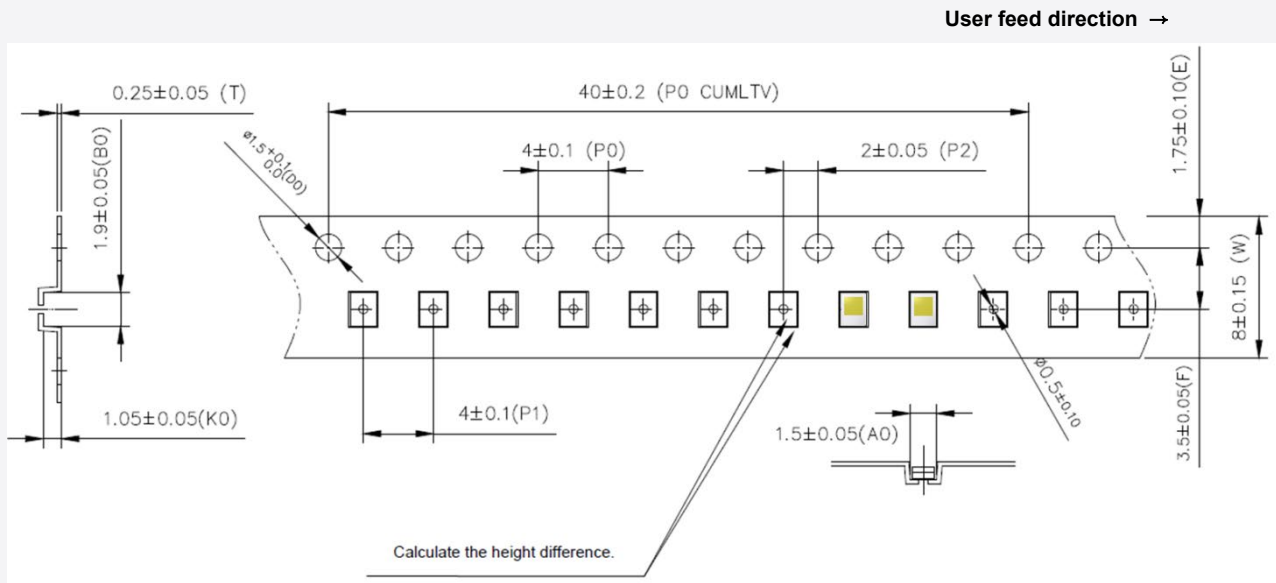


c) Manual Soldering Conditions

Not more than 5 seconds @ max. 300 °C, under soldering iron. (one time only)

7. Tape & Reel

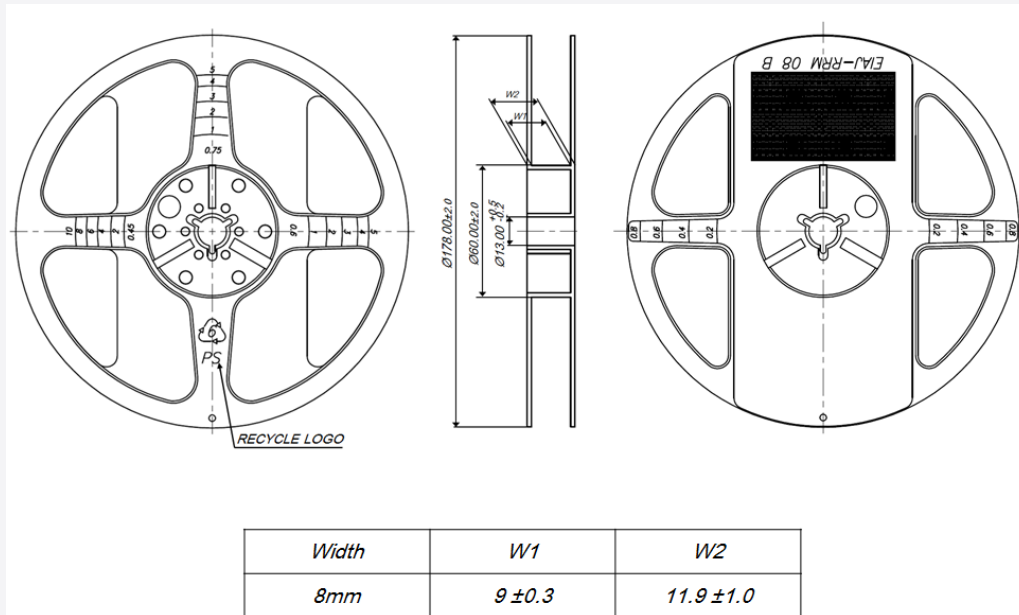
a) Taping Dimension



Notes:

Unit: mm, LED taping quantity: 3,000EA / Reel

b) Reel Dimension

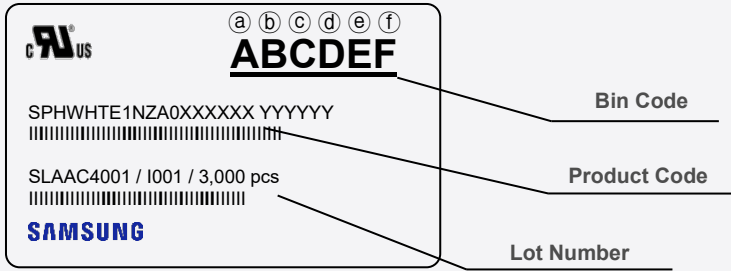


Notes:

Unit: mm, Tolerance: ±0.2mm

8. Label Structure

a) Label Structure



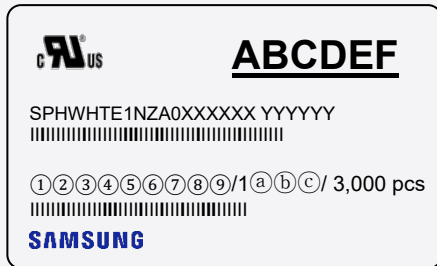
Note: Denoted bin code and product code above is only an example (see description on page 5)

Bin Code:

- a****b**: Forward Voltage bin (refer to page 5)
- c****d**: Chromaticity bin (refer to page 6)
- e****f**: Luminous Flux bin (refer to page 5)

b) Lot Number

The lot number is composed of the following characters:

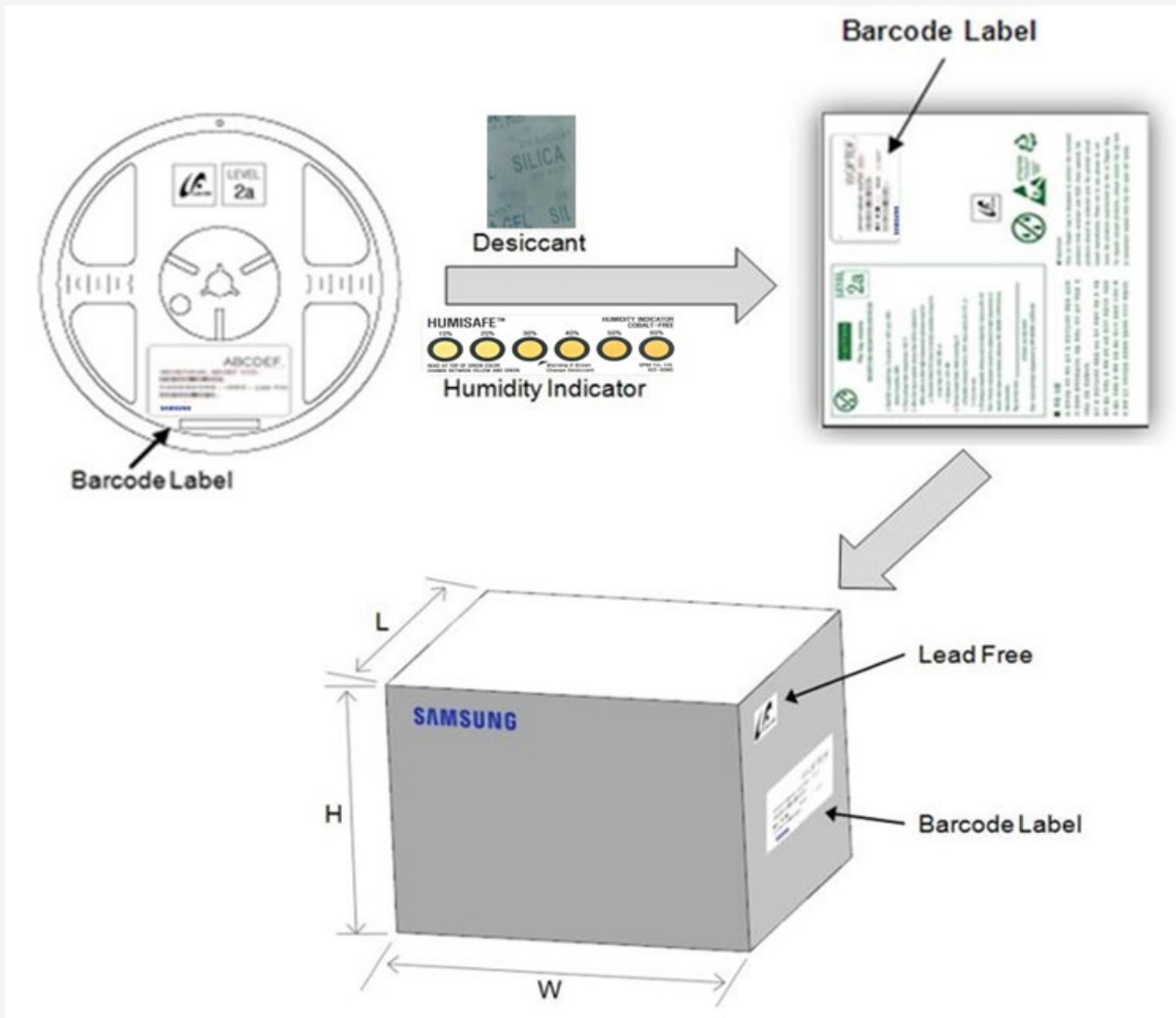


123456789 / 1abc / 3,000 pcs

①②	: Production site (SL : Kiheung, GA : Tienjin)
③	: Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
④	: Year (G: 2022, H: 2023, I: 2024...)
⑤	: Month (1~9, A, B, C)
⑥	: Day (1~9, A, B~V)
⑦⑧⑨	: Serial number (001 ~ 999)
①②③	: Product serial number (001 ~ 999)

9. Packing Structure

a) **Packing Process** (The quantity of PKG on the Reel to be Max 3,000pcs)



Dimension of Transportation Box in mm

Width	Length	Height
220	245	182

10. Precautions in Handling & Use

- 1) For over-current protection, we recommend the use of resistors to prevent sudden current surges caused by slight shifts in voltage.
- 2) LEDs should not be contacted to any type of fluid (i.e. water, oil, organic solvent, etc.). If cleaning is required, only use isopropyl alcohol.
- 3) The maximum ambient temperature must be considered in order for the maximum temperature ratings not to be exceeded.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for 3 months or more after being shipped from Samsung Electronics, they should be packed by a sealed container with nitrogen gas injected. (Shelf life of sealed bags: 12 months, temp. $\sim 40^{\circ}\text{C}$, $\sim 90\%$ RH)
- 5) After storage bag is open, LED subjected to soldering, solder reflow, or other high temperature processes must be:
 - a) Mounted within 8,760 hours (1 year) at an assembly line with a condition of no more than 30°C / 60% RH.
 - b) Stored at $<10\%$ RH.
- 6) Repack unused products using anti-moisture packing, fold to close any openings and store in a dry place with $<10\%$ RH
- 7) LEDs require baking before mounting, if humidity card reading is $>60\%$ at $23\pm 5^{\circ}\text{C}$.
- 8) If baking is required, LEDs must be baked for 1 day at $60\pm 5^{\circ}\text{C}$.
- 9) LEDs are sensitive to electrostatic discharge and surges. Applying any voltage exceeding the absolute maximum rating of the LED can cause permanent damage to the device. Damaged LEDs may have some unusual characteristics such as increased leakage current, lower turn-on voltage or may light abnormally at low current. When handling LEDs, using grounding wrist-bands or anti-static gloves is recommended.
- 10) VOCs (volatile organic compounds) present in adhesives, flux, hardeners or organic additives, etc. that are used in luminaires may lead to discoloration of the LED when exposed to heat or light. Note that VOCs can permeate silicone bags. This phenomenon can significantly affect light output from the luminaire. To avoid this issue, please carefully evaluate materials used in your process and/or luminaire to be free of VOCs.

11. Company Information

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